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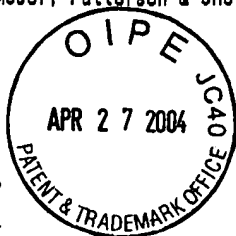
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ISSUE FEE TRANSMITTAL

TITLE: BURIED RIBBON SEMICONDUCTOR LASER AND A METHOD OF FABRICATION
U.S. SERIAL NO.: 10/066,641
FILING DATE: 02/06/2002
INVENTOR: NOUREDDINE BOUADMA
EXAMINER: LEITH A. AL NAZER
GROUP ART UNIT: 2828
CONFIRMATION NO.: 4521

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